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600V N-Channel Power MOSFET





TO-220



Pin Definition:

- 1. Gate 2. Drain
- 3. Source

Key Parameter Performance

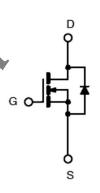
Parameter	Value	Unit
$V_{ t DS}$	600	V
R _{DS(on)} (max)	1.6	
Q_g	18.3	nC

Ordering Information

Part No.	Package	Packing
TSM6NB60CZ C0G	TO-220	50pcs / Tube
TSM6NB60CI C0G	ITO-220	50pcs / Tube

Note: `G_denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings (T_C = 25° less otherwise noted)

Parameter		Symbol	Limit		Unit
			TO-220	ITO-220	Unit
Drain-Source Voltage		V_{DS}	600		V
Gate-Source Voltage		V_{GS}	±3	30	V
Continuous Drain Current	$T_C = 25^{\circ}C$	I _D	6		A
	$T_C = 100$ °C		3.6		
Pulsed Drain Current (Note 2)		I _{DM}	24		Α
Total Power Dissipation @ T _C =25°C		P _{DTOT}	125	40	W
Single Pulsed Avalanche Energy (Note 3)		E _{AS}	83		mJ
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150		°C

Thermal Performance

Parameter	Symbol	ool Limit		Unit
Junction to Case Thermal Resistance	R _{∄IJC}	1	3.1	°C/W
Junction to Ambient Thermal Resistance	R _{∄IJA}	62.5	65	°C/W







Electrical Specifications (T_C = 25°C unless otherwise noted)

Conditions	Symbol	Min	Тур	Max	Unit	
Static (Note 4)						
$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	600			V	
$V_{DS} = V_{GS}, I_D = 250\mu A$	$V_{GS(TH)}$	2.5	3.6	4.5	V	
$V_{GS} = \pm 30V, V_{DS} = 0V$	I _{GSS}			±100	nA	
$V_{DS} = 600V, V_{GS} = 0V$	I _{DSS}			10	μΑ	
$V_{GS} = 10V, I_{D} = 3A$	R _{DS(on)}		1.12	1.6	- 1	
	Q _g		18.3			
1 20 , 2 ,	Q _{gs}	\\	5.26		nC	
V _{GS} = 10V			6.84			
	jss		872			
, 40 ,	C _{oss}		104		рF	
T = 1.UMHZ	C _{rss}		15			
4	t _{d(on)}		23			
$V_{DD} = 30 \text{ V}, R_{GEN} = 25 \text{ J}, t_r$		9.4				
$I_D = 6$, $V_{GS} = 10V$,	t _{d(off)}		05.0	ns		
	t _f		6.8			
Source-Drain Diode						
$I_{S} = 6A, V_{GS} = 0V$	V_{SD}			1.4	٧	
	$\begin{aligned} &V_{GS} = 0V, \ I_D = 250 \mu A \\ &V_{DS} = V_{GS}, \ I_D = 250 \mu A \\ &V_{GS} = \pm 30V, \ V_{DS} = 0V \\ &V_{DS} = 600V, \ V_{GS} = 0V \\ &V_{GS} = 10V, \ I_D = 3A \end{aligned}$ $\begin{aligned} &V_{DS} = 480V, \ I_D = 6A, \\ &V_{GS} = 10V \end{aligned}$ $\begin{aligned} &V_{DS} = 25V, \ V_{GS} = 0V, \\ &f = 1.0MHz \end{aligned}$ $\begin{aligned} &V_{DD} = 30V, \ R_{GEN} = 25 , \\ &I_D = 6A, \ V_{GS} = 10V, \end{aligned}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 10mH, $I_{AS} = 3.9A$, $V_{DD} = 50V$, $R_G = 25$, Starting $T_J = 25$ °C
- 4. Pulse test: PW #300μs, duty cycle #2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.

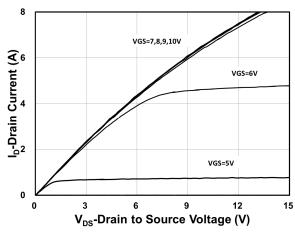


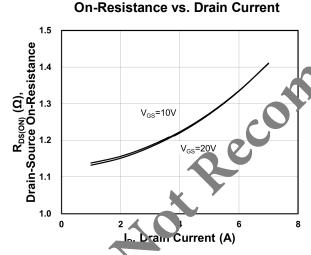
600V N-Channel Power MOSFET



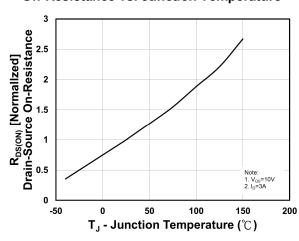
Electrical Characteristics Curves



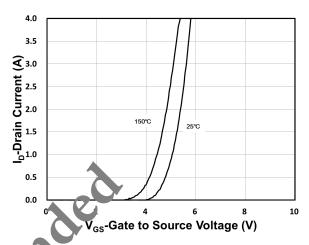




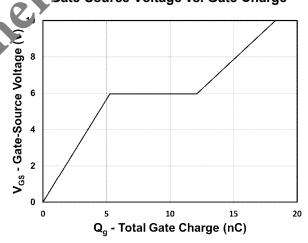
On-Resistance vs. Junction Temperature



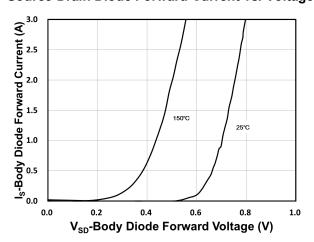
Transfer Characteristics



Sate-Source Voltage vs. Gate Charge



Source-Drain Diode Forward Current vs. Voltage



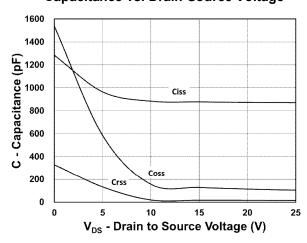


600V N-Channel Power MOSFET

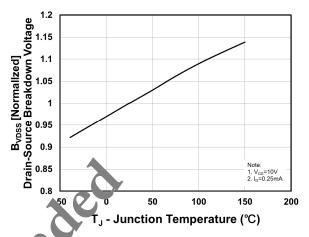


Electrical Characteristics Curves

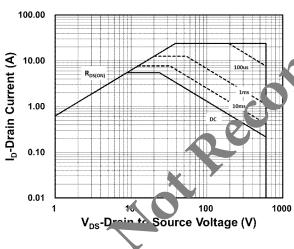
Capacitance vs. Drain-Source Voltage



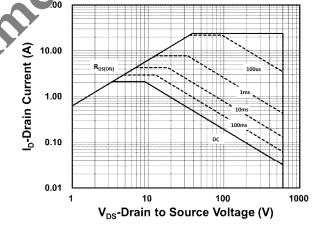
BV_{DSS} vs. Junction Temperature



Maximum Safe Operating Area (TO-220)



Maximum Safe Operating Area (ITO-220)



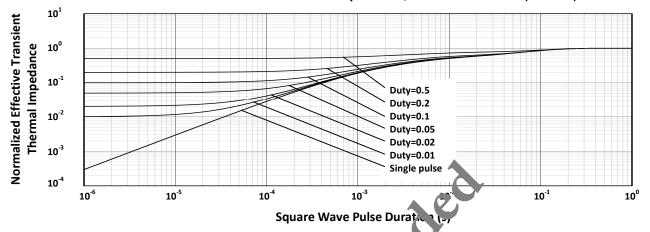


600V N-Channel Power MOSFET

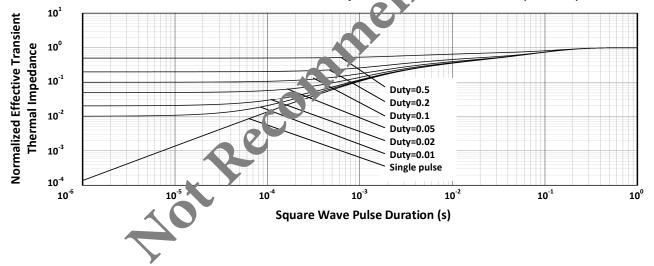


Electrical Characteristics Curves





Normalized Thermal Transient Impedan e, Junction-to-Case (ITO-220)

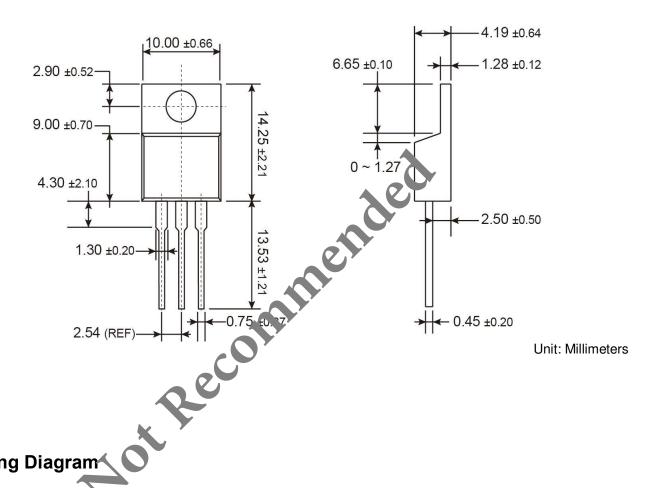




600V N-Channel Power MOSFET



TO-220 Mechanical Drawing



Marking Diagram



= Year Code

M = Month Code for Halogen Free Product (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

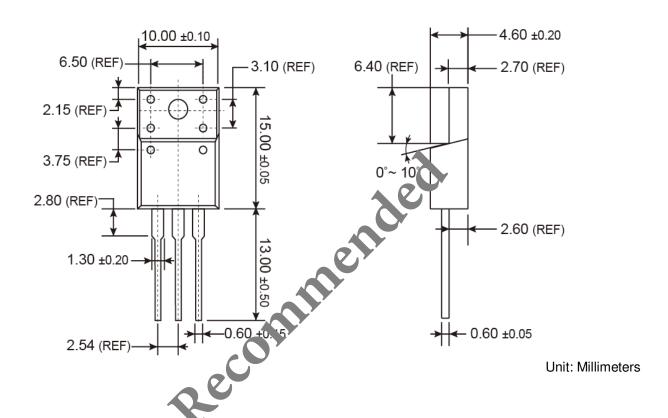
= Lot Code







ITO-220 Mechanical Drawing



Marking Diagram



G = Halogen Free

Y = Year Code

WW = Week Code (01~52)

F = Factory Code



TSM6NB60600V N-Channel Power MOSFET

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